

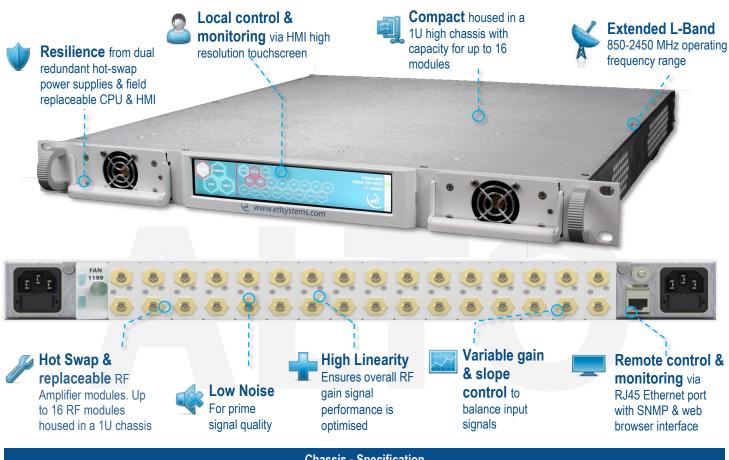
Model Number: ALT-G1S-S3-100A-xxxx

Typical applications:

- Teleports & Earth Stations
- Satellite Operations
- Government & Defence applications
- Telemetry, Tracking & Command
- High Resilience applications

Alto Extended L-band Smart Amplifier Module with low noise, high linearity, variable gain and slope control

The extended L-Band low noise amplifier module is designed to work in the Genus 1U chassis series, operating over 850-2450 MHz. The module has low noise, high linearity, +45 to -4 dB variable gain with variable slope control. The chassis has the capacity for up to 16 amplifier modules, or can house a mixture of other hot-swap module types.



Chassis - Specification		
Dimensions / Weight / Colour	1U high x 550mm deep x 19" wide / <10 kg / RAL9003—White (Semi-matte)	
Capacity	Total of 17 module slots. Note that 1 slot may be used for fan (if required) and 1 slot may be used for 10 MHz EXT inject module (if required). Note actual modules may require >1 slot. Refer to required module spec table.	
Temperature	Operating: 0°C to +45°C / Storage: -20°C to +75°C	
Location / Humidity / Altitude	Indoor use only / 20 to 90% non-condensing / 10,000 feet AMSL (Operational) 30,000 feet AMSL (Storage) Above Mean Sea Level	
Control & Monitoring	Local: HMI touch screen Remote: Ethernet via RJ45, 10BaseT/100 BaseTx. TCP/IP, SNMP V3 & HTTPS & Web browser interface HMI and CPU field replaceable. Each module independently monitored and reported.	
MTTR	20 minutes (15 minutes to retrieve spare part and 5 mins to replace) Applies to LRUs only and assumed in house stock	
AC Input / Consumption	85-264Vac 50/60Hz / 150W	
PSU Redundancy	Dual redundant and alarmed Diode OR. Hot swappable	
Input & Output ports	Dependant upon module fitted	















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Smart Amplifier Module
Compact form factor allowing multiple
modules to be housed in 1U chassis. Each module uses 1 slot in the chassis.

		Smart Amplifier Module - RF Parameters		
Model Numbers		ALT-G1S-S3-100A-xxxx		
Frequency Range RF Connectors		850-2450 MHz		
		50Ω SMA 50Ω N-type		
Gain (dB)	Max.	45±2		
	Min.	-4±2		
Gain Flatness (dB)	850 to 2450 MHz	±0.6		
	Any 36 MHz	±0.2		
Gain Steps (dB)		0.25±0.15		
Slope Control Range	e (dB)	0 to 8. Pivot point at 2450 MHz		
Slope Control Steps (dB)		1±0.25		
Input Return Loss (dB)		18 typ. 14 min		
Output Return Loss (dB)		18 typ. 14 min		
Isolation (dB)	Тур.	60. With amplifiers set at the same gain level. Worst case isolation is between adjacent amps, isolation degrades dB-to-dB for different gain levels.		
	Min.	50 With amplifiers set at the same gain level. Worst case isolation is between adjacent amps, isolation degrades dB-to-dB for different gain le	vels.	
Reverse Gain (dB)		< -60 Typical		
Noise Figure (dB)	Тур.	2.0 At max gain setting		
	Min.	3.0 At max gain setting		
1 dD CCD (dD)	Тур.	23 At max gain setting		
1dB GCP (dBm)	Min.	20 At max gain setting		
OIDO (ID)	Тур.	35 At max gain setting		
OIP3 (dBm)	Min.	32 At max gain setting		
OIP2 (dBm)	Тур.	45		
	Min.	41		
In band, signal indep	pendent spurii	<-85 dBm max. Very low level spuria from CPU clock, switch mode PSU and other control electronics inside the chassis		
Operating Temperature		0 to 50°C and for indoor use only		
Humidity		20 to 90% non-condensing RH		
MTBF		>150,000 hrs. MTBF of each amp module. These are hot-swap		
Maximum Input Level		+20 dBm. For no damage. None operational.		
Module Weight		0.35 kg		
Spec Version		1.1		

Note 1: The specification is subject to regular reviews and will be updated from time to time as part of our continuing product development and improved spec accuracy. Note 2: Operation beyond the quoted limits stated above may cause instantaneous and permanent damage.

Note 3: All specs are for 50 Ohm connectors unless detailed otherwise.













